TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

# TC74VHC04F,TC74VHC04FT,TC74VHC04FK

#### Hex Inverter

The TC74VHC04 is an advanced high speed CMOS INVERTER fabricated with silicon gate  $C^2MOS$  technology.

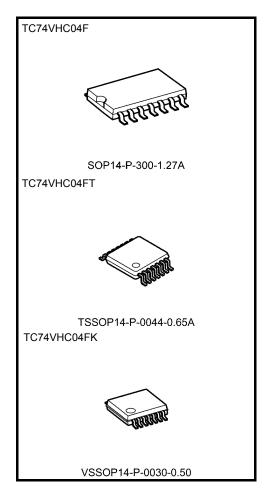
It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

The internal circuit is composed of 3 stages including buffer output, which provide high noise immunity and stable output.

An input protection circuit ensures that 0 to 5.5~V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5~V to 3~V systems and two supply systems such as battery back up. This circuit prevents device destruction due to mismatched supply and input voltages.

#### **Features**

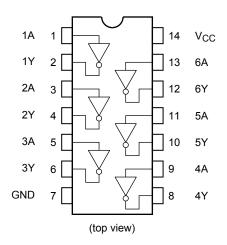
- High speed:  $t_{pd} = 3.8 \text{ ns (typ.)}$  at  $V_{CC} = 5 \text{ V}$
- Low power dissipation:  $I_{CC} = 2 \mu A$  (max) at  $T_a = 25$ °C
- High noise immunity:  $V_{NIH} = V_{NIL} = 28\% V_{CC}$  (min)
- Power down protection is provided on all inputs.
- Balanced propagation delays:  $t_{pLH} \simeq t_{pHL}$
- Wide operating voltage range:  $V_{CC \text{ (opr)}} = 2 \text{ V to } 5.5 \text{ V}$
- Low noise:  $V_{OLP} = 0.8 \text{ V (max)}$
- Pin and function compatible with 74ALS04



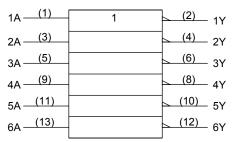
Weight

SOP14-P-300-1.27A : 0.18 g (typ.) TSSOP14-P-0044-0.65A : 0.06 g (typ.) VSSOP14-P-0030-0.50 : 0.02 g (typ.)

### **Pin Assignment**



### **IEC Logic Symbol**



#### **Truth Table**

| Α | Υ |
|---|---|
| L | Н |
| Н | L |

### **Absolute Maximum Ratings (Note)**

| Characteristics                    | Symbol           | Rating                        | Unit |
|------------------------------------|------------------|-------------------------------|------|
| Supply voltage range               | V <sub>CC</sub>  | −0.5 to 7.0                   | V    |
| DC input voltage                   | V <sub>IN</sub>  | −0.5 to 7.0                   | V    |
| DC output voltage                  | V <sub>OUT</sub> | -0.5 to V <sub>CC</sub> + 0.5 | V    |
| Input diode current                | Ιικ              | -20                           | mA   |
| Output diode current               | lok              | ±20                           | mA   |
| DC output current                  | lout             | ±25                           | mA   |
| DC V <sub>CC</sub> /ground current | Icc              | ±50                           | mA   |
| Power dissipation                  | PD               | 180                           | mW   |
| Storage temperature                | T <sub>stg</sub> | −65 to 150                    | °C   |

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).



# **Operating Ranges (Note)**

| Characteristics          | Symbol           | Rating  | Unit   |
|--------------------------|------------------|---|--------|
| Supply voltage           | $V_{CC}$         | 2.0 to 5.5                                    | V      |
| Input voltage            | V <sub>IN</sub>  | 0 to 5.5                                      | V      |
| Output voltage           | V <sub>OUT</sub> | 0 to V <sub>CC</sub>                          | V      |
| Operating temperature    | T <sub>opr</sub> | −40 to 85                                     | °C     |
| Input rise and fall time | dt/dv            | 0 to 100 ( $V_{CC} = 3.3 \pm 0.3 \text{ V}$ ) | ns/V   |
|                          | didv             | 0 to 20 ( $V_{CC} = 5 \pm 0.5 \text{ V}$ )    | 113/ V |

Note: The operating ranges must be maintained to ensure the normal operation of the device. Unused inputs must be tied to either VCC or GND.

### **Electrical Characteristics**

### **DC Characteristics**

| Characteristics Symbol    |                 | Test Condition                    |  | Ta = 25°C                       |                                   |                        | Ta =<br>−40 to 85°C               |                                   | Unit                              |    |
|---------------------------|-----------------|-----------------------------------|--|---------------------------------|-----------------------------------|------------------------|-----------------------------------|-----------------------------------|-----------------------------------|----|
|                           |                 |                                   | V <sub>CC</sub> (V)                                    | Min                             | Тур.                              | Max                    | Min                               | Max                               | O.I.I.                            |    |
| High-level input voltage  | V <sub>IH</sub> | _                                 |  | 2.0<br>3.0 to 5.5               | 1.50<br>V <sub>CC</sub> ×<br>0.7  | _<br>_                 | _<br>_                            | 1.50<br>V <sub>CC</sub> ×<br>0.7  | _<br>_                            | ٧  |
| Low-level input voltage   | V <sub>IL</sub> | _                                 |  | 2.0<br>3.0 to 5.5               | _                                 | _<br>_                 | 0.50<br>V <sub>CC</sub> ×<br>0.3  | _<br>_                            | 0.50<br>V <sub>CC</sub> ×<br>0.3  | ٧  |
| High-level output voltage | V <sub>ОН</sub> | $V_{IN} = V_{IL}$                 | $I_{OH} = -50 \mu A$ $I_{OH} = -4 mA$ $I_{OH} = -8 mA$ | 2.0<br>3.0<br>4.5<br>3.0<br>4.5 | 1.9<br>2.9<br>4.4<br>2.58<br>3.94 | 2.0<br>3.0<br>4.5<br>— | _<br>_<br>_<br>_                  | 1.9<br>2.9<br>4.4<br>2.48<br>3.80 | -<br>-<br>-                       | ٧  |
| Low-level output voltage  | V <sub>OL</sub> | $V_{IN} = V_{IH}$                 | $I_{OL} = 50 \mu A$ $I_{OL} = 4 mA$ $I_{OL} = 8 mA$    | 2.0<br>3.0<br>4.5<br>3.0<br>4.5 |                                   | 0.0<br>0.0<br>0.0<br>— | 0.1<br>0.1<br>0.1<br>0.36<br>0.36 | -<br>-<br>-                       | 0.1<br>0.1<br>0.1<br>0.44<br>0.44 | V  |
| Input leakage current     | I <sub>IN</sub> | V <sub>IN</sub> = 5.5 V or GND    |  | 0 to 5.5                        | -                                 | _                      | ±0.1                              | -                                 | ±1.0                              | μΑ |
| Quiescent supply current  | I <sub>CC</sub> | V <sub>IN</sub> = V <sub>CC</sub> | or GND   | 5.5                             | _                                 | _                      | 2.0                               | _                                 | 20.0                              | μΑ |



### AC Characteristics (input: $t_r = t_f = 3 \text{ ns}$ )

| Characteristics Symb          | Symbol          | Test Condition |                                |                     | Ta = 25°C |      |      | Ta =<br>−40 to 85°C |      | Unit |
|-------------------------------|-----------------|----------------|--------------------------------|---------------------|-----------|------|------|---------------------|------|------|
|                               | -,              | -,             | V <sub>CC</sub> (V)            | C <sub>L</sub> (pF) | Min       | Тур. | Max  | Min                 | Max  |      |
| Propagation delay time tphLH  |                 |                | $3.3 \pm 0.3$<br>$5.0 \pm 0.5$ | 15                  | _         | 5.0  | 7.1  | 1.0                 | 8.5  | - ns |
|                               | · ·             |                |                                | 50                  | _         | 7.5  | 10.6 | 1.0                 | 12.0 |      |
|                               |                 |                |                                | 15                  | _         | 3.8  | 5.5  | 1.0                 | 6.5  |      |
|                               |                 |                |                                | 3.0 ± 0.3           | 50        | _    | 5.3  | 7.5                 | 1.0  | 8.5  |
| Input capacitance             | C <sub>IN</sub> | _              |                                |                     | _         | 4    | 10   | _                   | 10   | pF   |
| Power dissipation capacitance | C <sub>PD</sub> |                |                                | (Note)              | 1         | 18   | -    | _                   | _    | pF   |

Note: C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

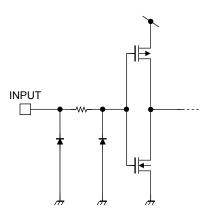
Average operating current can be obtained by the equation:

 $I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/6 \text{ (per gate)}$ 

### Noise Characteristics (input: $t_r = t_f = 3$ ns)

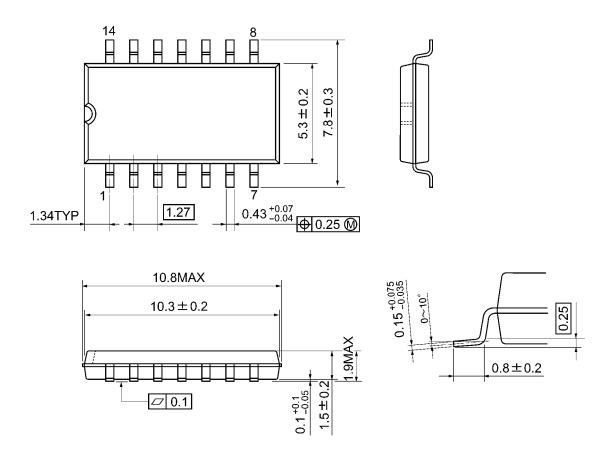
| Characteristics                              | Symbol           | Test Condition         | Ta =                | - Unit |       |      |
|--|------------------|------------------------|---------------------|--------|-------|------|
|  |                  |                        | V <sub>CC</sub> (V) | Тур.   | Limit | Uill |
| Quiet output maximum dynamic V <sub>OL</sub> | V <sub>OLP</sub> | C <sub>L</sub> = 50 pF | 5.0                 | 0.4    | 8.0   | V    |
| Quiet output minimum dynamic V <sub>OL</sub> | V <sub>OLV</sub> | C <sub>L</sub> = 50 pF | 5.0                 | -0.4   | -0.8  | V    |
| Minimum high level dynamic input voltage     | V <sub>IHD</sub> | C <sub>L</sub> = 50 pF | 5.0                 | _      | 3.5   | V    |
| Maximum low level dynamic input voltage      | V <sub>ILD</sub> | C <sub>L</sub> = 50 pF | 5.0                 | _      | 1.5   | V    |

### **Input Equivalent Circuit**



# **Package Dimensions**

SOP14-P-300-1.27A Unit: mm

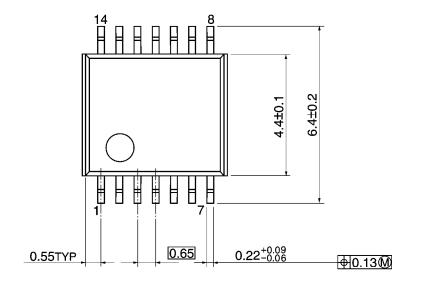


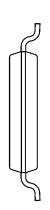
Weight: 0.18 g (typ.)

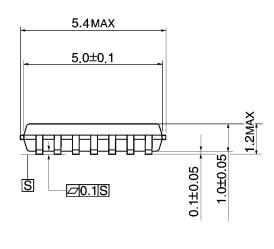
# **Package Dimensions**

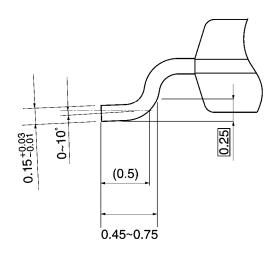
TSSOP14-P-0044-0.65A

Unit: mm





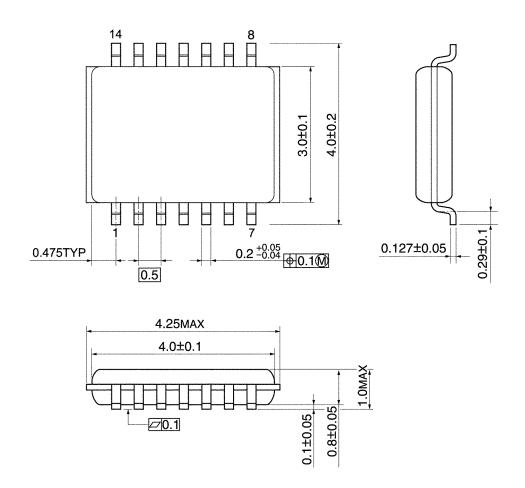




Weight: 0.06 g (typ.)

# **Package Dimensions**

VSSOP14-P-0030-0.50 Unit: mm



Weight: 0.02 g (typ.)

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